## NSN 5962-01-058-6739

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View Online at https://aerobasegroup.com/nsn/5962-01-058-6739

Body Length:
Between 0.370 inches and 0.434 inches
Body Width:
Between 0.240 inches and 0.290 inches
Body Height:
Between 0.049 inches and 0.090 inches
Maximum Power Dissipation Rating:
660.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set type an/aps-125
Features Provided:
Hermetically sealed and monolithic and programmable and programmed and w/enable and w/buffered output
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output and 60.00 nanoseconds.
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Special Features:
Bit pattern table no. 6
Test Data Document:
27963-57991100 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

N/a

16 flat leads

Shelf Life:

**Terminal Type And Quantity:** 

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Demilitarization:

Yes - demil/mli

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